

PJD45P03E-AU **30V P-Channel Enhancement Mode MOSFET TO-252AA** -30 V Current -42 A Voltage **Features** • Rds(ON), Vgs@-10V, Id@-20A<15mΩ • Rds(ON), Vgs@-4.5V, Id@-10A<26mΩ • 100% UIS tested • Reliable and Rugged • AEC-Q101 qualified 2 Drain • Lead free in compliance with EU RoHS 2.0 • Green molding compound as per IEC 61249 standard (1) Gate **Mechanical Data**

Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.3217 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-30		
Gate-Source Voltage		V _{GS}	±25		
Continuous Drain Current ^(Note 3)	T _C =25°C		-42		
	Tc=100°C	I _D	-30	A	
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	-128		
Power Dissipation	T _C =25°C	_	43		
	Tc=100°C	PD	21	W	
Continuous Drain Current ^(Note 4)	T _A =25°C		-11.2		
	T _A =70°C	I _D	-9.4	A	
Power Dissipation	T _A =25°C	D-	3	14/	
	T _A =70°C	PD	2.1	W	
Single Pulse Avalanche Energy ^(Note 5)		Eas	56	mJ	
Operating Junction and Storage Temperature Range		Tj,Tstg	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	$R_{ extsf{ heta}JC}$	3.5	00000	
	Junction to Ambient	R _{0JA}	50	°C/W	

Source



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Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	Vgs=0V, Id=-250uA	-30	-	-	- V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-1	-1.8	-2.5		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-20A	-	12	15	mΩ	
		V _{GS} =-4.5V, I _D =-10A	-	20	26		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1	uA	
	I _{GSS}	V _{GS} =±25V, V _{DS} =0V	-	-	±10	uA	
Gate-Source Leakage Current		V _{GS} =±10V, V _{DS} =0V	-	-	±1		
Dynamic ^(Note 6)							
Total Gate Charge	Qg		-	32	-	nC	
Gate-Source Charge	Qgs	V_{DS} =-24V, I_{D} =-20A,	-	5	-		
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	10	-		
Input Capacitance	Ciss		-	1270	-	pF	
Output Capacitance	Coss	V_{DS} =-25V, V_{GS} =0V,	-	190	-		
Reverse Transfer Capacitance	Crss	f=1MHz	-	170	-		
Gate resistance	Rg	f=1MHz	-	7	-	Ω	
Turn-On Delay Time	td _(on)		-	7	-		
Turn-On Rise Time	tr	V _{DS} =-24V, I _D =-20A,	-	9	-	ns	
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =3Ω	-	32	-		
Turn-Off Fall Time	tf		-	39	-		
Drain-Source Diode							
Diode Forward Current	Is	T 05°0	-	-	-42	A	
Pulsed Diode Forward Current	I _{SM}	Tc=25°C	-	-	-128		
Diode Forward Voltage	V _{SD}	Is=-20A, V _{GS} =0V	-	-0.9	-1.3	V	
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =-20A	-	18	-	ns	
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	8	-	nC	

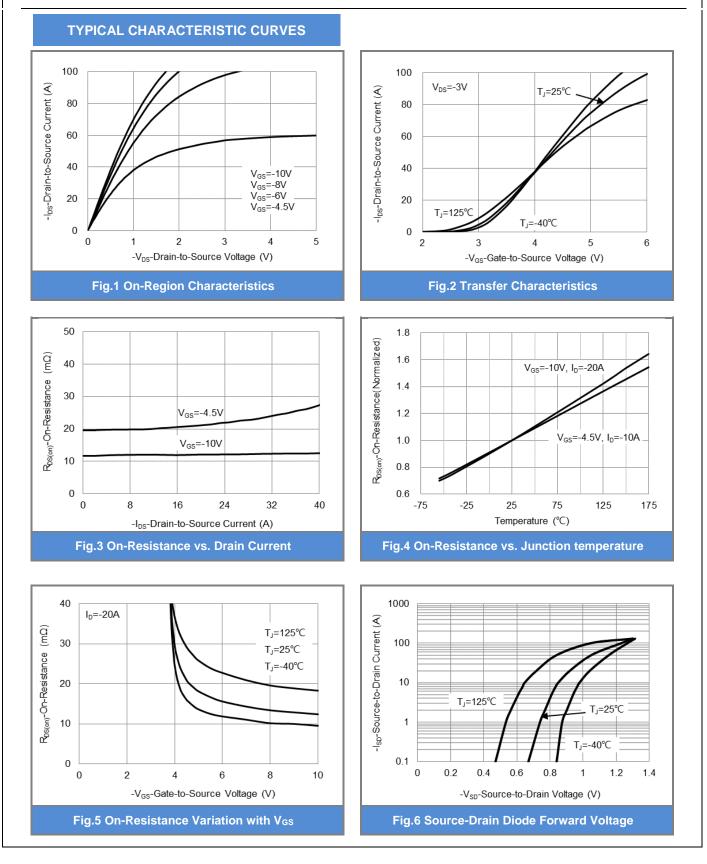
NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =-15A, V_{DD} =-30V, V_{GS} =-10V, Starting T_J =25°C.
- 6. Guaranteed by design, not subject to production testing.

SEMI CONDUCTOR

PANJ

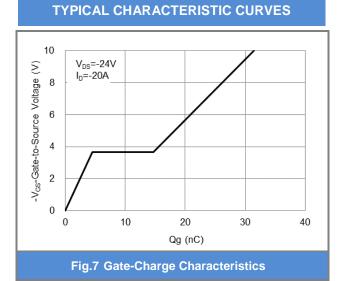
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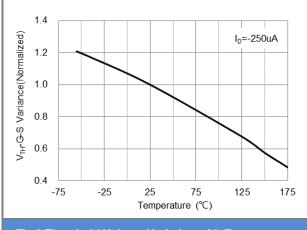


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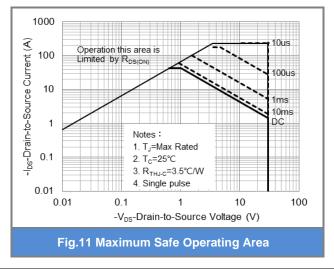
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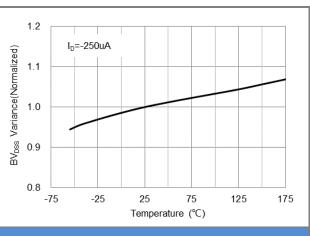
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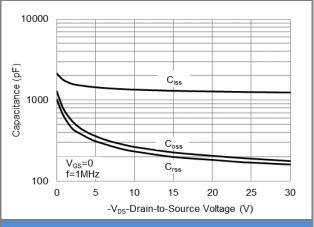
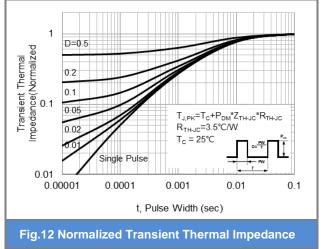


Fig.10 Capacitance vs. Drain-Source Voltage



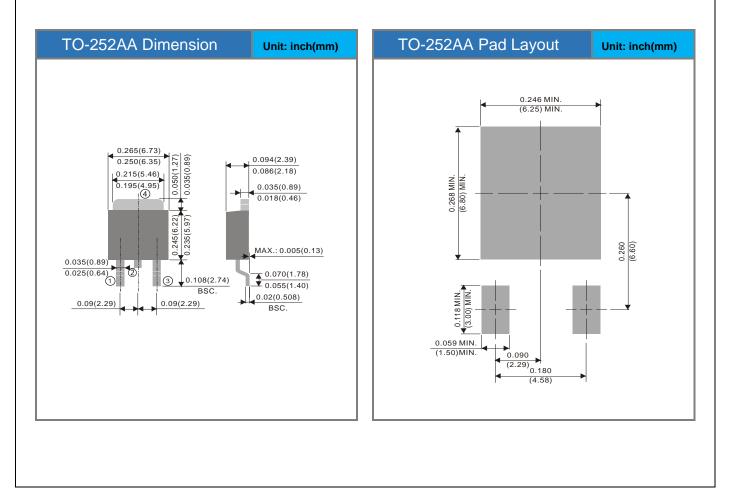


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJD45P03E-AU	TO-252AA	3K pcs / 13" reel	D45P03E	

Packaging Information & Mounting Pad Layout





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